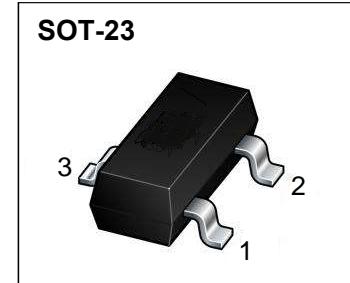


SOT-23 Plastic-Encapsulate ESD Protection Diodes

Features

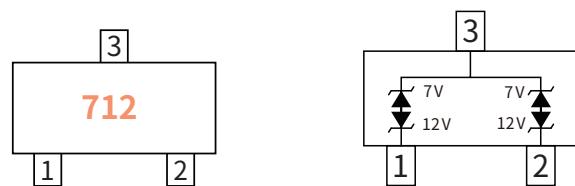
- Normal capacitance: $C_{1,2 \text{ to } 3} = 75 \text{ pF} (\text{Max.})$
- Protects two -7V to +12V lines
- Low leakage current
- IEC 61000-4-2 (ESD Air): $\pm 30 \text{ kV}$
- IEC 61000-4-2 (ESD Contact): $\pm 30 \text{ kV}$
- IEC 61000-4-5 (Lightning 8/20 μs): 12A



Applications

- Protection of RS-485 transceivers with extended common-mode range
- Security systems
- Automatic teller machines
- HFC systems
- Net works

Function Diagram

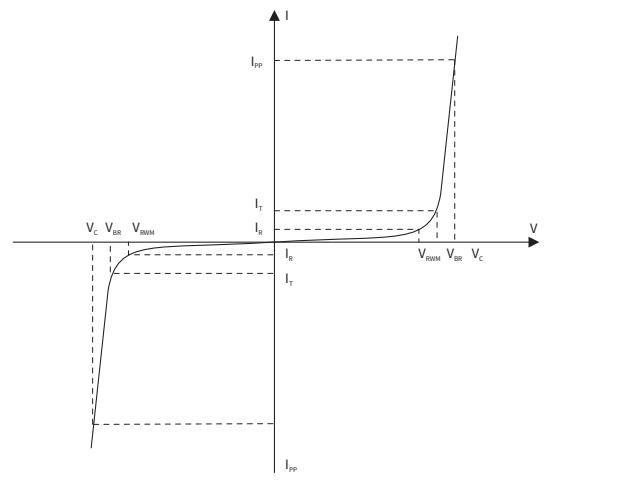


Maximum Ratings (Ta=25°C Unless otherwise specified)

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
V_{ESD}	Electrostatic Discharge Voltage	ESD per IEC 61000-4-2(Air)	± 30	kV
		ESD per IEC 61000-4-2(Contact)	± 30	kV
P_{PP}	Peak Pulse Power	$t_p = 8/20 \mu\text{s}$	300	W
I_{PP}	Rated Peak Pulse Current	$t_p = 8/20 \mu\text{s}$	12	A
T_J	Operating JunctionTemperature Range	—	-55 to +125	°C
T_{STG}	Operating JunctionTemperature Range	—	-55 to +150	°C

Electrical Parameter

SYMBOL	PARAMETER
V_C	Clamping Voltage @ I_{PP}
V_{BR}	Breakdown Voltage @ I_T
I_{PP}	Peak Pulse Current
I_T	Test Current
I_R	Reverse Leakage Current @ VRWM
V_{RWM}	Peak Reverse Working Voltage
P_{PP}	Peak Pulse Power Dissipation
C_J	Junction Capacitance @ $V_R=0\text{V}, f=1\text{MHz}$
I_F	Forward Current
V_F	Forward Voltage @ I_F



Electrical Characteristics (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	CONDITION	Pins 1/2 to 3 (12V)			Pins 3 to 1/2 (7V)			UNIT
			Min	Typ	Max	Min	Typ	Max	
Peak Reverse Working Voltage	V _{RWM}	T _a =25°C	-	-	12	-	-	7	V
Breakdown Voltage	V _{BR}	I _r =1mA, T _a =25°C	13.3	-	-	7.5	-	-	V
Reverse Leakage Current	I _R	V _R =V _{RWM} , T _a =25°C	-	-	1.0	-	-	1.0	μA
Clamping Voltage	V _C	I _{PP} =1.0A, t _p =8/20μs	-	-	18	-	-	12	V
		I _{PP} =12.0A, t _p =8/20μs	-	-	26	-	-	18	V
Junction Capacitance	C _J	V _R =0V, f=1MHz	-	-	100	-	-	100	pF
		V _R =V _{RWM} , f=1MHz	-	65	-	-	65	-	pF

Ratings And Characteristics Curves (Ta=25°C Unless otherwise specified)
